(7/12/1) Con. 6641-11.

GE ETRX Sem - TT CREVO AGJ 2nd half (f+) 17 B.A. D.C.A.

(REVISED COURSE)

(3 Hours)

MP-4312 [Total Marks : 100

N.B.:

- 1. Question No. 1 is compulsory.
- 2. Out of remaining questions, attempt any four questions.
- 3. In all <u>five</u> questions to be attempted.
- 4. All questions carry equal marks.
- 5. Answer to each new question to be started on a fresh page.
- 6. Figures in brackets on the right hand side indicate full marks.

| Q1.(A) Explain with block diagram a typical communication system. | (5) |
|--|------------------------|
| (B) The local oscillator frequency of superheterodyne AM broadcast receiver is key the signal frequency by an amount equal to intermediate frequency. Why? | ot above (5) |
| (C) A signal m(t)= 2 cos 6000πt + 4 cos 8000πt + 6 cos 10000πt is represented by sa What is minimum sampling rate from a)Low pass sampling theorem b)band pas consideration? | amples. s (5) |
| (D) "Double integration is used in the feedback path of delta modulation in case of communication" Justify. | voice (5) |
| Q2.(A) Explain noise figure for cascade stages. Calculate the overall noise figure for a r stage has a noise figure of 20 dB and this is preceded by an amplifier that has a figure of 9 dB and an available power gain of 15 dB. | nixer noise (10) |
| (B) Explain with block diagram DSB-SC modulator and demodulator. | (10) |
| Q3.(A) Show that DSB-SC amplitude modulation is linear while phase modulation is no | n linear. (5) |
| (B) Consider an angle modulated signal x(t)=3cos[2π10⁶t+2sin(2π10³t)]. Find(1) Instantaneous frequency at time 0.25ms and 0.5 ms. (2) Maximum phase and frequency deviation. | (5) |
| (C) Explain VSB signal generation and detection in details. | (10) |
| Q4.(A) In a broadcast superheterodyne receiver having no RF amplifier, the loaded Q o antenna coupling circuit is 100. If the IF is 455KHz, calculate. | f the |
| (2) The image frequency and its rejection ratio for tuning at 25MHz. | (10) |

Con. 6641-MP-4312-11.

(B) Explain TRF receiver with block diagram, also explain TRF sensitivity and TRF selectivity characteristics. (10)

7

- Q5.(A) Explain the process of quantizing in PCM. Determine the signal to noise ratio at the output. (10)
 - (B) "In PCM, SNR can be controlled by transmission bandwidth" Justify. Compare PCM and Delta modulation. (10)
- Q6.(A) Explain advantages and disadvantages of different PCM waveform formats. (10)
 - (B) Show that a limited signal of finite energy, which has no frequency components higher than W Hz may be completely recovered from a knowledge of its samples taken at the rate of 2W per seconds. (10)
- Q7.(A) What parameter of the signals is sampled by a Delta Modulator? While sampling speech waveform what should be the sampling rate to avoid slope overload? What parameter should be reduced to decrease the quantization noise power for a given sampling rate of the Delta Modulation ? (10)(10)
 - (B) Explain in details NBFM and WBFM .

SE ETRX - IV (R) EE MIM

| 29 | +12/11 SE ETRX - IX (R) | . : |
|---------------|--|-----|
| . | EE MIM | |
| Co | m. 6913-11. | 318 |
| | (3 Hours) [Total Marks : | 100 |
| N.I | B.: (1) Question No.1 is compulsory. (2) Attempt any four questions from the remaining six questions. (3) Assume suitable data if necessary. (4) Figures to the right indicate marks. | |
| | 1(A)Explain multi-range ohm-meter with diagram. | 05 |
| | (B) What is back emf? Explain significance of back emf. | 05 |
| | (C) Explain the function of delay line in oscilloscope. Which are the two types of delay lines? | 05 |
| | (D) State the requirements of a good laboratory type of signal generator. | .05 |
| | 2.(A) Draw and explain FET as a voltmeter. What are its sensitivity considerations? | 10 |
| | (B) Explain flash type ADC with suitable diagrams. | 10 |
| | 3.(A) Explain digital phase meter using flip flop. Write its advantages and disadvantages. | 10 |
| | (B) Expain the construction and working principle of Weston type frequency meter. | 10 |
| | 4.(A) Explain beat frequency oscillator and its advantages. | 10 |
| | (B) Explain analog storage oscilloscope. State the drawbacks of analog storage oscilloscope. | 10 |
| | 5(A) How will you find the value of capacitance with the help of schering bridge? Explain with the help of derivation and vector diagram | 10 |
| | (B) Explain the construction and working of electrodynamometer type power factor meter. | 10 |
| | 6.(A) Explain different methods of speed control of dc series motors. | 10 |
| | (B) Derive the torque equation for 3 phase induction motors. Explain v/f method of speed control of induction motors. | 10 |
| | | 20 |
| • | 7. Write short note on (any three):- | 20 |
| • | (A) megger | |
| | (B) variable reluctance stepper motor | |
| | (C) deivation of torque equation for moving iron meters. | |
| | (D) Gear wheel method in CRO. | |

ws Sept-2011-148 Con. 6052-11.

2/12/11 SE. (ETRX) Sem-IV Advanced Engineering MP-4324

(3 Hours) Mathematics [Total Marks: 100

- **N. B.**: (1) Question No. 1 is compulsory.
 - (2) Attempt any four questions out of the remaining six questions.
 - (3) Figures to the right indicate full marks.
- (a) A sample of 100 students is taken from a large population. The mean hight of 5 1. the students in this sample is 160 cm. Can it reasonably regarded that in the population, the mean height is 165 cm. and S.D. is 10 cm. 5
 - (b) If λ_1 , λ_2 , λ_3 are the Eigen values of the matrix
 - $\begin{vmatrix} -2 & -9 & 5 \\ -5 & -10 & 7 \\ -9 & -21 & 14 \end{vmatrix}$

then find $\lambda_1 + \lambda_2 + \lambda_3$ and $\lambda_1 \lambda_2 \lambda_3$.

- (c) Evaluate $\int_{c} \frac{\sin^{6} z}{(z \pi/e)^{3}} dz$, where c is |z| = 1.
- (d) A random variable X has the probability function $f(x) = \frac{4x}{81} (9-x^2), 0 \le x \le 3$ 5 find first four moments about mean.
- (a) Find the expectation of (i) the sum (ii) the product of the number of points on 6 2. the throw of n-dice.
 - (b) P.T $G = \{1, -1, i, -i\}$ is a group under usual multiplication of complex numbers.
 - (c) Two undepedent samples of sizes 8 and 7 gave the following results -

| the difference | hotw | | moló r | noane | cignific | ont 2 | | |
|----------------|------|----|--------|-------|----------|-------|----|--|
| Sample 2 : | 15 | 14 | 15 | 19 | 15 | 18 | 16 | |
| Sample 1 : | 19 | 17 | 15 | 21 | 16 | 18 | 16 | |

is the difference between sample means significant?

(a) Determine Eigen values and Eigen vectors for the following matrix :-3.

$$A = \begin{bmatrix} 8 & -6 & 2 \\ -6 & 7 & -4 \\ 2 & -4 & 3 \end{bmatrix}$$

- (b) Let A be a set of non-zero integers and let R be a relation on A X A defined by 6 (a, b) R(c, d) if ab = bc.
- The marks obtained by students in a college are normally distributed with mean 8 (C) 65 and variance 25. If 3 students are selected at random from college, what is the probability that atleast one of them would have scored more than 75 marks?

TURN OVER

5

6

8

6

ws Bept-2011-149 Con. 6052-MP-4324-11.

- 2/12/11 S.E. (ETRX) Sem-IV Advanced Engineering Mathematics
- 4. (a) The probability mass function of a random variable X is zero excepts at the points X = 0, 1, 2. At these points it has the values $P(0) = 3C^3$, $P(1) = 4C 10C^2$, $P(2) = 5C^{-1}$. Determine C, find P(X < 1), $P(1 < X \le 2)$, $P(0 < X \le 2)$.

2

- (b) If $f: R \to R$, $g: R \to R$ are defined as $f(x) = 2x^2 + 5$ and g(x) = 3x + 5 then find **6** gof, fof, g^{-1} of. Does f^{-1} exist ? Justify your answer.
- (c) If $f(\xi) = \int_{c} \frac{4z^2 + z + 5}{z \xi} dz$ where c is the ellipse, find the values of f(i), f'(-1), **8** f''(-i) and f(3).
- 5. (a) If X denotes the out comes when a fair die is tossed, find M.G.F. of X and hence 6 find mean and variance of X.
 - (b) Determine the nature of poles of the following function and find the residue of **6** each pole $f(z) = z^2 e^{\gamma z}$.
 - (c) Show that the set of matrices $M = \begin{bmatrix} a & b \\ -5b & a \end{bmatrix}$, $ab \in z$ form an integral domain. Is **8** it a field 2

it a field ?

6. (a) Obtain two distinct Laurent's series for $f(z) = \frac{2z-3}{z^2-4z-3}$ in power of (z - 4) 6

indicating the regions of convergence.

(b) Show that the matrix $A = \begin{bmatrix} 1 & -6 & -4 \\ 0 & 4 & 2 \\ 0 & -6 & -3 \end{bmatrix}$ is similar to a diagonal matrix. Also find **6**

the transforming matrix and the diagonal matrix.

(c) According to Genetic theory children having one parent of blood type M and the other of blood type N will always be one of three types M, MN and N and the average proportions of these types will be 1 : 2 : 1 out of 300 children, having one M parent and one N parent, 30 percent were found to be of type M, 45% of MN and remaining of type N. Test the Genetic theory by χ^2 test.

8

6

- 7. (a) A transmission channel has a per-digit error probability p = 0.01. Calculate the probability of more than 1 error in 10 received digit using
 - (i) Binomial Distribution (ii) Poisson Distribution.
 - (b) Check whether A = $\{2, 4, 12, 16\}$ and B = $\{3, 4, 12, 24\}$ are lattices under divisibility. **6** Draw their Hasse diagrams.
 - (c) Find the characteristic equation of the matrix A given below and hence find the matrix represented by $A^8 5A^7 + 7A^6 3A^5 + A^4 5A^3 + 8A^2 2A + 1$

where $A = \begin{bmatrix} 2 & 1 & 1 \\ 0 & 1 & 0 \\ 1 & 1 & 2 \end{bmatrix}$

AGJ 2nd half (d+) 31

Con. 6519-11.

(3 Hours)

SE

N.B.: (1) Question No.1 is compulsory.

13/12/2011

- (2) Attempt any four questions from question Nos. 2 to 7.
- (3) Assume suitable data wherever necessary with proper justification.
- (4) Figures to the right indicate full marks.
- Attempt any four of the following :-1.
 - (a) Derive an expression for the Miller input & output capacitance for inverting amplifier.
 - (b) Explain Series-fed Class A power Amplifier,
 - (c) For current series negative feedback derive the expression of the input resistance with feedback.
 - (d) State the methods to improve CMRR of a Differential amplifier & explain any one.
 - (e) Write a note on Darlington Pair.
- 2. Design a two stage RC coupled CS amplifier for zero temperature drift for following 20 requirements: F₁ better than 15Hz using JFET BFW11(Max) with |Av| = 49 & Vo = 3V.
- 3 (a) Explain Class B push Pull amplifier with waveforms & derive expression for its 10 maximum efficiency.
 - (b) Determine the lower cutoff frequency for the network given below :



- (a) For Dual input balanced output BJT differential amplifier derive the expression for 4. 10 input resistance, output resistance & voltage gain. (b) Explain the high frequency analysis of a BJT amplifier. Derive necessary expressions. 10
- 5. ·10 (a) Compare different types of Negative feedback amplifiers, (b) For a class B amplifier with Vcc=30V driving an 16 Ω load, Determine 10 (a) Maximum input power, (b) Maximum output power, (c) Maximum circuit efficiency, (d) Transistor dissipation.

[TURN OVER

20

MP-4322

[Total Marks : 100

Con. 6519-MP-4322-11.

6. (a) Identify the type of Negative feedback for following circuit & determine A, β , A_f, 10 $Z_{if}, Z_{of} \& A_{vf}$



(b) Draw the circuit diagram of Hartley oscillator & explain its working. Derive the 10 necessary equation for frequency of oscillations & for sustaining oscillations.

- - (a) MOSFET Differential amplifier
 - (b) Cross over distortion in class B Power amplifier
 - (c) Cascode amplifier
 - (d) RC phase shift Oscillator.

DBEC DATA SHEET

| Transistor | Pdmex | l cmex | V _{CE(ast)} | | V | V | V | V | T, | D.C. | current | gain | Small | Signal | h _{te} | Vae | 0, | Derate |
|-----------------|--------------------|--------------------|----------------------|---------------|----------------|----------------|---------------|----------------|-----------|------|---------|------|-------|--------|-----------------|------|-----|-----------------------|
| type | C 25°C Watta | Q 25°C Amps. | voits d.c. | volts d.c. | (Sus) volts | (Sus) volts | voits d.c. | voita d.c. | max. ℃ | .min | typ. | mex. | min. | typ. | max. · | max. | •CW | sbove 25°C W/°C |
| 2N 3055 | 115.5 | 15.0 | 1.1 | 100 | 60 | 70 | 90 | -7 | 200 | 20 | - 50 | 70 | 15 | 50 | 120 | 1.8 | 1.5 | 0.7 |
| ECN 055 | 50.0 | 5.0 | 1.0 | 60 | 50 | 55 | 60 | 5 | 200 | 25 | 50 | 100 | 25 | 75 | 125 | 1.5 | 3.5 | 0.4 |
| ECN 149 | 30.0 | 4.0 | 1.0 | 50 | 40 | - | · _ | 8 | 150 | 30 | 50 | 110 | 33 | 60 | 115 | 1.2 | 4.0 | 0.3 |
| ECN 100 | 5.0 | 0.7 | 0.6 | 70 | 60 | 65 | - | 15 | 200 | 50 | 90 | 280 | 50 | 90 | 280 | 0.9 | 35 | 0.05 * |
| BC 147A | 0.25 | 0.1 | 0.25 | 50 | 45 | 50 | - | ^A 6 | 125 | 115 | 180 | 220 | 125 | 220 | 260 | 0.9 | - | - |
| 2N 525 (PNP) | 0.225 | 0.5 | 0.25 | 85 | 30 | - | - | - | 100 | 35 | · | 65 | - | 45 | - | - | - ' | - |
| BC 147 B | 0.25 | 0.1 | 0.25 | 50 | 45 | 50 | _ | 6 | 125 | 200 | 290 | 450 | 240 | 330 | 500 | 0.9 | - | - |

| Transistor type | h, ie | h | h | 0 ja |
|--------------------|----------|------------|------------------------|----------|
| BC 147 A | 2.7kΩ | 18µmho | 1.5 × 10 ⁻⁴ | 0.4°C/mW |
| 2N 525 (PNP) | 1.4kΩ | 25µmho | 3.2×10^{-4} | |
| BC 147B | 4.5kΩ | 30µmho | 2 × 10 ⁻⁴ | 0.4°C/mW |
| ECN 100 | 50Ω | . – | • | |
| ECN 149 | 15Ω | | - | |
| ECN 055 | 120 | _ 2 | | |
| 2N 3055 | 6Ω | | | · . |

BFW 11-JFET MUTUAL CHARACTERISTICS

| -V _{as} volts | 0.0 | 0.2 | 0,4 | 0.6 | 8.0 | 1.0 | 1.2 | 1.6 | 2.0 | 2.4 | 2.5 | 3.0 | 3,5 | 4.0 |
|----------------------------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| l _{ps} max. mA | 10 | 9.0 | 8.3 | 7.6 | 6.8 | 6.1 | 5.4 | 4.2 | 3.1 | 2.2 | 2.0 | 1.1 | 0.5 | 0.0 |
| los typ. mA | 7.0 | 6.0 | 5.4 | 4.6 | 4.0 | 3.3 | 2.7 | 1.7 | 0.8 | 0.2 | 0.0 | 0.0 | 0.0 | 0.0 |
| I _{pe} min.mA | 4.0 | 3.0 | 2.2 | 1.6 | 1.0 | 0.5 | 0.0 | 0.0 | 0.0 | 0.0 | 0.0 | 00 | 0.0 | 0.0 |

N-Channel JFET

| Туре | V _{DS max.} Volts | V _{DG max.} Volts | V _{GS max.} Volts | P _{d max.} @ 25°C | Tj max, | 1 _{Dez} | g _{me} (typical) | -V _p Volts | t _e | Denste above 25°C | 9 ,n |
|---------------------|-------------------------------|-------------------------------|-------------------------------|-------------------------------|---------|------------------|------------------------------|-----------------------|----------------|----------------------|------------|
| 2N3822 | 50 | 50 | - 50 | 300 mW | 175°C | 2 mA | 3000 µ mho | 6 | 50 ΚΩ | 2 mW/°C | 0.59°C/ntW |
| BFW 11 (typical) | 30 | `30 | 30 | . Wm 068 | 200°C | 7 mA | 5600 μ mho | 2.5 | 50 ΚΩ | | 0.59°C/mW |

Con

6519-MP-4322-11.

~

5.2

8/12/2011 SE (ETRX) IV (R) DSD-T

AGJ 2nd half (y) 48

1.

2.

3.

4.

5.

Con. 6287-11.

MP-4315

(3 Hours)

[Total Marks : 100

5

5

5

5

10

10⁻

10

10

10

10

10

- N.B.: (1) Question No. 1 is compulsory.
 - (2) Attempt any four out of remaining six questions.
 - (3) Assume any **suitable** data wherever required and justify the **same**.
 - A. List the predefined types for signal declaration in VHDL
 B. Write VHDL code for 4:1 multiplexer using selected signal
 - assignment statement
 - C. Explain Moore and Melay sequential circuits
 - D. What is the need of state assignment rules? Explain the state assignment rules
 - A. Design Mod 120 counter using IC 7493 and few gates
 B. Write VHDL code for twisted ring counter
 - A. Design a 3 bit synchronous counter controlled by input W. If W=1 the counter adds 2 to its contents. wrapping around if the counter overflows. Thus if the present state is 6 or 7 the next state becomes 0 or 1 respectively. If W=0 then the counter subtracts 1 from its contents acting as normal down counter. Make use of T flip flops and active low output decoders for the generation of excitation inputs.
 - B Draw and explain 6T SRAM cell
 - A Write VHDL code for mod 8 asynchronous counter using structural modeling.
 - B. Design 16x1 diode ROM. Use two dimensional decoding 10 approach
 - A. Draw and explain architecture of XILINX 9500 family CPLD in detail.
 - B, Analyze the pulse mode asynchronous sequential machine given below and obtain transition table, flow table and state diagram of the circuit.



[TURN OVER

Con. 6287-MP-4315-11.



B. Reduce the state of the following state table using implication chart method

| PS | N | S | O/P | | | | | |
|------------|------------|-----|-----|-----|--|--|--|--|
| | X=0 | X=1 | X=0 | X=1 | | | | |
| S 0 | S2 | S1 | 0. | 0 | | | | |
| S1 | S4 | S3 | 0 | 0 | | | | |
| S2 | S6 | S5 | 0 | 0 | | | | |
| S3 | S0 | S0 | 1 | 1 | | | | |
| S4 | S0 | S0 | 0 | 0 | | | | |
| S5 | SO | S0 | 1 | 1 | | | | |
| S6 | S 0 | S0 | Ő | 0 | | | | |

Design a clocked synchronous state machine with two inputs x 10 and y and one output z. The output should be 1 if the number of 1 inputs on x and y since reset is multiple of 4 and otherwise output z should be 0

B. Write notes on

7.

- i) Dynamic RAM
- ii) Applications of Shift registers

.

10

10

6, A, Analyze the clocked sequential synchronous circuit given below